			1.00	Time otamp
L Number	Hits	Search Text	DB USPAT;	Time stamp 2002/05/17 11:22
-	696	(438/400).ccls. and @ad<=20011206	US-PGPUB;	2002/03/17 11:22
			EPO; JPO;	
			DERWENT;	
[IBM TDB	!
-	6	((438/400).ccls. and @ad<=20011206) and	USPAT;	2002/05/17 11:26
	·	ONO	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
	0	@ad<=20011206 and 'ONO structure' with	USPAT;	2002/05/17 12:35
		'buffer layer'	US-PGPUB;	
			EPO; JPO;	
			DERWENT; IBM TDB	
-	000	 @ad<=20011206 and 'ONO structure'	USPAT;	2002/05/17 12:01
	290	@ad<=20011206 and ONO Scructure	US-PGPUB;	2002,00,1. 12:01
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	160	@ad<=20011206 and 'Oxide' with 'SiON' with	USPAT;	2002/05/17 12:31
_	100	'Sin' with 'SiON' with 'Oxide'	US-PGPUB;	
		DIN WICH DION WITH OWING	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	3	@ad<=20011206 and 'ONO structure' and	USPAT;	2002/05/17 12:40
		'buffer layer'	US-PGPUB;	
		-	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	1	@ad<=20011206 and 'multi dielectric layer'	USPAT;	2002/05/17 12:43
		and 'memory'	US-PGPUB;	2
			EPO; JPO;	
			DERWENT;	
		2.1.1.2.1.2.2.2.2.2.2.2.2.2.2.2.2.2.2.2	IBM_TDB	2002/05/17 12:47
-	26		USPAT; US-PGPUB;	2002/03/17 12.47
		and 'memory'	EPO; JPO;	
			DERWENT;	
			IBM TDB	
	0	@ad<=20011206 and 'O-SiON-N-SiON-O'	USPĀT;	2002/05/17 12:49
-	"	ead(-20011200 and 0 blok k blok o	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
1_	1393	@ad<=20011206 and oxide and SiON and	USPAT;	2002/05/17 12:55
		Nitride and SiON and oxide	US-PGPUB;	
			EPO; JPO;	1
}			DERWENT;	
			IBM_TDB	0000/05/13 10:50
-	0	@ad<=20011206 and oxide adj SiON adj	USPAT;	2002/05/17 12:56
		Nitride adj SiON adj oxide	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		0.0000000000000000000000000000000000000	IBM_TDB	2002/05/17 14:31
-	300		USPAT; US-PGPUB;	2002/03/11 14.31
		'nitride' with 'SiON' with 'oxide'	EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
	107	(@ad<=20011206 and 'oxide' with 'SiON'	USPAT;	2002/10/28 09:13
-	10/	with 'nitride' with 'SiON' with 'oxide')	US-PGPUB;	
		and memory	EPO; JPO;	
		and memory	DERWENT;	
			IBM TDB	
_	540	@ad<=20011206 and (438/778).ccls.	USPAT;	2002/05/17 14:32
-	1 340		US-PGPUB;	
}			EPO; JPO;	
	1		DERWENT;	
			IBM TDB	
1	1			

Search History 10/28/02 2:00:06 PM Page 1 C:\APPS\east\workspaces\Dielectric Formation or SOG\10002978 ONO with Buffer layers.wsp

<i>i</i> -	2862	((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 08:49
	2002	or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	2002/10/28 08:49
		or (438/770) or (438/775)).CCLS.	EPO; JPO;	
		OI (430/770) OI (430/773/).CCI3.	DERWENT;	
			IBM TDB	1
	2356	((257/324) or (257/314-315) or (257/406)	USPAT;	2002/10/28 08:41
_	2356	or (257/410)).CCLS.	US-PGPUB;	2002/10/28 08:41
	1	or (257/410)).CCLS.		
			EPO; JPO;	
			DERWENT;	t
-	_		IBM_TDB	1
	7	(((100), (10), 01), 01, 01, 01, 01, 01, 01, 01, 01, 01, 01	USPAT;	2002/10/28 08:59
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	-
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'silane' with 'nitrogen	DERWENT;	
		oxide'	IBM_TDB	
_	6328	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:03
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
	-	or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'SiON' or 'silicon	DERWENT;	
		oxynitride'	IBM TDB	
_	0		USPĀT;	2002/10/28 09:04
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	2002, 20, 20 03.01
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and SiH4 with N20 with NH3	DERWENT;	İ
		Gad\-20011200 and Sin4 with N20 with N115	IBM TDB	İ
		////20/770\ om //20/707\ om //20/700 701\	_	2002/10/20 00-00
_	8	' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' ' '	USPAT;	2002/10/28 09:09
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'SiON' with 'deposition'	DERWENT;	
	ļ		IBM_TDB	
-	448	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:11
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'ammonia'	DERWENT;	
			IBM TDB	
-	190	(((438/778) or (438/787) or (438/790-791)	USPAT;	2002/10/28 09:11
		or (438/794) or (438/400) or (438/769-770)	US-PGPUB;	
		or (438/770) or (438/775)).CCLS.) and	EPO; JPO;	
		@ad<=20011206 and 'ammonia' and 'silane'	DERWENT;	İ
			IBM TDB	
-	194	@ad<=20011206 and 'ammonia' and 'silane'	USPĀT;	2002/10/28 09:16
		and 'nitrogen oxide'	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	}
<u> </u>	350	@ad<=20011206 and 'oxide' with 'SiON' with	IBM TDB	2002/10/00 00 12
	359	· · · · · · · · · · · · · · · · · · ·	USPAT;	2002/10/28 09:13
		'nitride' with 'SiON' with 'oxide'	US-PGPUB;	I .
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
Ī	27	@ad<=20011206 and 'ammonia' same 'silane'	USPAT;	2002/10/28 09:19
		same 'nitrogen oxide'	US-PGPUB;	
	1		EPO; JPO;	1
			LIO, OLO,	1
			DERWENT;	